	Specification	Symbol	Condition / C	omment			61-30	SiC	121-30 SiC	151-30 SiC	Unit
	Maximum Operating Voltage	$V_{O(max)}$	I <sub>off</sub> < 50 μADC, T <sub>case</sub> = 70°C				6	6	12	15	kVDC
	Maximum Isolation Voltage	Vı	Between HV switch and control / GND, continuously						± 25		kVDC
RATINGS	Max. Housing Insulation Voltage	Vins	Between switch and housing surface, 3 minutes						± 50		kVDC
	Maximum Turn-On Peak Current	$I_{P(max)}$	T <sub>case</sub> = 25°C						300		
4					duty cycle <1%				190		
					t <sub>p</sub> < 10 ms, duty cycle <1% t <sub>p</sub> < 100 ms, duty cycle <1%				58		400
5				-					30		ADC
1	Maximum Continuous Load Current	I <sub>L(max)</sub>	T <sub>case</sub> = 25°C	Standard devices					2.52		400
MAXIMUM	May Continuous Day on Discinution	D		Devices with option DLC			4	_	60	10.5	ADC
_	Max. Continuous Power Dissipation	P <sub>d(max)</sub>	T <sub>case</sub> = 25°C Standard devices & FC, forced air 4 m/s Devices with option DLC			4. 60		8.5 1450	10.5 1600	Watt	
5	Linear Derating			Standard devices & EC forced air / m/s			0.0		0,03	0.033	vvall
70	Emour Bordang		Above 25°C Devices with option DLC			1		20	21	W/K	
ABSOLUTE	Operating Temperature Range	To	Standard devices & options CF, GCF, ILC. (Option DLC)				-	-4070 (60)		°C	
4	Storage Temperature Range	Ts	Switches with option ILC may require frost protection!						-4090		°C
	Max. Permissible Magnetic Field	В	Homogeneous steady-field, surrounding the whole switch						25		mT
	Max. Auxilliary Voltage	Vaux	Built-in overvoltage limiter (replaceable)						5.5		VDC
	Permissible Operating Voltage Range	Vo	<del>_</del>			0	± 6	0 ± 12	0 ± 15	kVDC	
	Typical Breakdown Voltage	$V_{br}$	NOTE: V <sub>br</sub> is a test parameter for quality control purposes only. Not applicable in normal operation! I <sub>off</sub> > 0.5 mA				6.	6	9.3	11.6	kVDC
	Typical Off-State Current	I <sub>off</sub>		0.8xV <sub>O</sub> , T <sub>case</sub> =2570°C, reduced I <sub>off</sub> on request					< 80		μADC
	Typical Turn-On Resistance	R <sub>stat</sub>		Each switching path 0.1 x I <sub>P(max)</sub> , T <sub>case</sub> =25°C			0.1	12	0.24	0.28	†
			t <sub>p</sub> < 1µs, duty cy	ycle < 1%	1.0 x I <sub>P(max)</sub> , T <sub>ca</sub>		0.25		0.5	0.6	
			1.0 x I <sub>P(ma</sub>				0.	5	0.9	1.3	Ohm
	Typical Propagation Delay Time	$t_{d(on)}$	Resistive load, 0.1 x I <sub>P(max)</sub> , 0.8 x V <sub>O(max)</sub> , 50-50%						200		ns
	Typical Output Pulse Jitter	tj	Impedance matched input, V <sub>aux</sub> / V <sub>ctrl</sub> = 5						3		ns
	Typical Turn-On Rise Time	t <sub>r(on)</sub>	Resistive load, 10-90% 0.1 x V <sub>O(max)</sub> ,				tb		19	tbd.	
					0.8 x V <sub>O(max)</sub> , I <sub>L</sub>		tb.		34	tbd.	
SS	Turing Turn Off Diag Time	4 4	Desiri - 1 - 1 40 000/			$O_{(max)}$ , $I_L = 1.0 \text{ x } I_{p(max)}$		<b>a</b> .	41	tbd.	ns
	Typical Turn-Off Rise Time	$t_{\text{off}}, t_{\text{q}}$	Resistive load, 10-90% $0.1 \times V_{O(max)}$ , $I_L = 0.1 \times I_{p(max)}$					50 100		ns	
Ĭ	Marriago de Timo	1	0.8 x V <sub>O(max)</sub> , I <sub>L</sub> = 1.0 x I <sub>p(max)</sub>								_
CHARACTERISTICS	Maximum Turn-On Time Minimum Turn-On Time	ton(max)	No limitation						∞ 250		ns
TE	Maximum Turn-Off Time	ton(min)	ton(min) can be customized. Please consult factory  No limitation						∞		ns ns
740	Minimum Turn-Off Time	t <sub>off(min)</sub>	toff(min) can be customized. Please consult factory						250		ns
A A	Max. Continuous Switching	f <sub>(max)</sub>	@ V <sub>aux</sub> = 5.00 V Standard devices without HFS option				tb	d.	10	tbd.	- 110
3	Frequency	(max)	Sw. shutdown if	Ü				d.	tbd.	tbd.	
4	, ,		f <sub>(max)</sub> is exceeded					d.	tbd.	tbd.	kHz
ELECTRICAL	Maximum Burst Frequency	f <sub>b(max)</sub>	Use option HFE	Use option HFB for >10 pulses within 20µs or less					2		MHz
E	Maximum Number of Pulses / Burst	N <sub>(max)</sub>	@ f <sub>b(max)</sub> Standard					>100			
TE(			Note: Option HFB requires external buffer capacitors with a voltage Option I-HFB						>1000		
W		rating of > 630VDC and a cpacitance of 100nF per additional pulse. Option HFB						>10000		Pulses	
	Coupling Capacitance	HV side against control side						<100 <50		pF	
	Natural Capacitance Control Voltage Range	Between switch poles, @ 0.5 x V <sub>O(max)</sub> The V <sub>ctrl</sub> has no impact on the output pulse shape.						3 10		pF VDC	
	Auxiliary Supply Voltage Range	The +5 V supply is not required in the HFS mode.						4.5 5.5		VDC	
	Typical Auxiliary Supply Current	V <sub>aux</sub>	$V_{aux} = 5.00 \text{ VDC}$ , $T_{case} = 25^{\circ}\text{C}$ . $0.01 \text{ x f}_{(max)}$			13	30	150	160	+ 150	
	Typical Admirary Supply Surrent		Active current limitation above 1A.		80		800	800	mADC		
	Fault Signal Output		Switch will be turn off, if f>f <sub>(max)</sub> , V <sub>aux</sub> <4.75V or T <sub>case</sub> >75°C						>4.0		
			Fault condition is indicated by a logical "L"						<0.8		VDC
	Opt. HFS, Ext. Supply Voltage V1	V <sub>HFS(V1)</sub>	Stability ±3%, current consumption <0.4 mA/kHz @ 25°C						15		VDC
	Opt. HFS, Ext. Supply Voltage V2 V <sub>HFS(V2)</sub> Stability ±3%, current consumption					/kHz @ 25°C	5		86	100	VDC
	Intrinsic Diode Forward Voltage							6	24	28	VDC
	iode Reverse Recovery Time t <sub>rrc</sub> T <sub>case</sub> = 25°C, I <sub>F</sub> = 0.3 x I <sub>P(max)</sub> , di/dt = 100 A/µs imensions LxWxH Standard housing						400.	70.05	<250ns	475.75.50	ns
HOUSING	Dimensions	Standard housi	ŭ			103x7 tb		103x70x35	175x75x56 tbd.	mm <sup>3</sup>	
	Devices with option DLC						l lb	u.	tbd.	ιου.	1111111
Ž	Weight Standard housing								tbd.		
Ħ	Devices with option DLC										g
	Control Signal Input    Din 4   Vollage / C. C. Din 4) TTL compatible // C. C. MEth. 4000 Accessive from C.						ohmi# T-i-	or oboro-t-	otion Control	2 10 1/2 5 1/5-1-	iitto=/
FUNCTIONS	Control Signal Input Logic GND / 5V Return Pin 2 / Black (LS-C: Pin 1). TTL compatible (LS-C: With 100Ω termination). Scheme Pin 2 / Black (LS-C: Shielding). The ground pin is internally connected with the								_		jitter).
	•	3, 3 ,						-			
	1	Red (LS-C: Pin 4). The 5 V input is used for rep rates up to the specified Drange (LS-C: Pin 3). TTL output, short circuit proof. Indicating switch &									
Š	I I										
5	LED Indicators  GREEN: "Auxiliary power good, switch OFF". YELLOW: "Control signal received."								•		
9/	Temperature Protection   Switches with option DLC: 65°C, response time < 3 s @ 3xPd(max), \( \Delta T = 25K \) (40 to 6 \)  HTS 61-30 SiC   Fast HV SiC Mosfet Switch, 6kV, 300 A   Option LP   Low Pass. Input filter for increased noise immunity.						Option I-PC Integrated part components according to customer specification.				
	HTS 121-15 SiC Fast HV SiC Mosfet Switch, 12kV, 300 A Option HFB High Frequency Burst (improved capability by external ca						pacitors) Option UL-94 Flame retardant casting resin, UL94-V0				
	HTS 151-30 SiC Fast HV SiC Mosfet Sw							Option I-FWD	Integrated Free-Wheeling D	iode. In connection with inductive	
N/S			Option I-HFS Integrated High Frequency Burst  Option S-TT Soft Transition Time decrease the rise and fall time by 20%					Option I-FWDN Option PT-C		ode Network. In connection with in :: Flexible leads (I=75mm) with len	
ORDERING			Option Min-On Individually increased "Min. On-Time" to avoid unwanted					Option SEP-C		trol unit with LED indicators in a se	
OR			Option Min-Off Individually increased "Min. Off-Time" to avoid unwanted				triggering	Option TH	Tubular Housing		
		Option PCC Pulser Configuration. Switch combined with custom specification option ISO-40 40kV Isolation. Isolation Voltage increased to 120kV.				fic parts. Option CF Copper Cooling Fins. P <sub>d(max)</sub> can be increased by the factor 3 to 10.  Option DLC Direct Liquid Cooling. P <sub>d(max)</sub> can be increased by the factor 10 to 100.					
		Option ISO-40 40kV Isolation. Isolation Voltage increased to 120kV.  Option ISO-60 60kV Isolation. Isolation Voltage increased to 200kV.				FOR FURTHER PRODUCT OPTIONS PLEASE REFER TO THE OPTIONS					